

## **General Description**

The WSP4409 is the highest performance trench P-Ch MOSFET with extreme high cell density, which provide excellent RDSON and gate charge for most of the synchronous buck converter applications.

The WSP4409 meet the RoHS and Green Product requirement, 100% EAS guaranteed with full function reliability approved.

#### **Features**

- Advanced high cell density Trench technology
- Super Low Gate Charge
- Excellent CdV/dt effect decline
- 100% EAS Guaranteed
- Green Device Available

## **Product Summery**

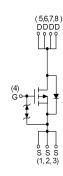
BVDSS	RDSON	ID
-30V	5.0mΩ	-17.6A

### **Applications**

Power Management in Notebook Computer,
Portable Equipment and Battery Powered Systems.
HBM ESD protection level pass 8KV.

# **SOP-8 Pin Configuration**





### **Absolute Maximum Ratings**

Symbol	Parameter Rating		Units	
$V_{DS}$	Drain-Source Voltage	-30	V	
$V_{GS}$	Gate-Source Voltage $\pm 20$			
I <sub>D</sub> @T <sub>c</sub> =25℃	Continuous Drain Current, V <sub>GS</sub> @ -10V <sup>1</sup>	-17.6	Α	
I <sub>D</sub> @T <sub>c</sub> =70°C	Continuous Drain Current, V <sub>GS</sub> @ -10V <sup>1</sup> -14		Α	
I <sub>DM</sub>	300uS Pulsed Drain Current <sup>2</sup> -70		А	
EAS	Single Pulse Avalanche Energy <sup>3</sup>	72	mJ	
I <sub>AS</sub>	Avalanche Current	-38	Α	
P <sub>D</sub> @T <sub>A</sub> =25℃	Total Power Dissipation⁴	4.2	W	
T <sub>STG</sub>	Storage Temperature Range	-55 to 150	$^{\circ}$	
$T_J$	Operating Junction Temperature Range	-55 to 150	$^{\circ}$	

#### **Thermal Data**

Symbol	Parameter	Тур.	Max.	Unit	
R <sub>0JA</sub>	Thermal Resistance Junction-Ambient <sup>1</sup>		75	°C/W	
R <sub>eJC</sub>	Thermal Resistance Junction-Case <sup>1</sup>		24	°C/W	



## Electrical Characteristics (T<sub>J</sub>=25 °C, unless otherwise noted)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	$V_{GS}$ =0V , $I_D$ =-250uA	-30			V
$\triangle BV_{DSS}/\triangle T_{J}$	BV <sub>DSS</sub> Temperature Coefficient	Reference to 25℃ , I <sub>D</sub> =-1mA		-0.018		V/℃
D	Static Drain-Source On-Resistance <sup>2</sup>	V <sub>GS</sub> =-10V , I <sub>D</sub> =-17.6A		5	7.2	mΩ
$R_{DS(ON)}$		V <sub>GS</sub> =-4.5V , I <sub>D</sub> =-10A		9	12	
$V_{GS(th)}$	Gate Threshold Voltage	V =V L = 2500A	-1.3	-1.8	-2.3	V
$\triangle V_{GS(th)}$	V <sub>GS(th)</sub> Temperature Coefficient	$V_{GS}=V_{DS}$ , $I_D=-250uA$		5.04		mV/℃
	Drain Source Loakage Current	$V_{DS}$ =-24V , $V_{GS}$ =0V , $T_J$ =25 $^{\circ}$ C			-1	uA
I <sub>DSS</sub>	Drain-Source Leakage Current	$V_{DS}$ =-24V , $V_{GS}$ =0V , $T_{J}$ =55 $^{\circ}$ C			-5	
I <sub>GSS</sub>	Gate-Source Leakage Current	$V_{GS}$ = $\pm 20 V$ , $V_{DS}$ = $0 V$			±100	nA
gfs	Forward Transconductance	V <sub>DS</sub> =-5V , I <sub>D</sub> =-10A		18		S
$Q_g$	Total Gate Charge (-4.5V)			45		
$Q_{gs}$	Gate-Source Charge	V <sub>DS</sub> =-15V,V <sub>GS</sub> =-4.5V,I <sub>D</sub> =-17.6A		5		nC
$Q_{gd}$	Gate-Drain Charge			12.7		
T <sub>d(on)</sub>	Turn-On Delay Time			12		
Tr	Rise Time	$V_{DD}$ =-15 $V$ , $V_{GS}$ =-10 $V$ , $R_G$ =6 $\Omega$ ,		14		no
$T_{d(off)}$	Turn-Off Delay Time	I <sub>D</sub> =-1A ,RL=15Ω		98		ns
T <sub>f</sub>	Fall Time			60		
C <sub>iss</sub>	Input Capacitance			2110	2956	
Coss	Output Capacitance	V <sub>DS</sub> =-15V , V <sub>GS</sub> =0V , f=1MHz		450	500	pF
C <sub>rss</sub>	Reverse Transfer Capacitance			330	385	

#### **Guaranteed Avalanche Characteristics**

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
EAS	Single Pulse Avalanche Energy <sup>5</sup>	V <sub>DD</sub> =-25V , L=0.5mH , I <sub>AS</sub> =-38A	60			mJ

# **Diode Characteristics**

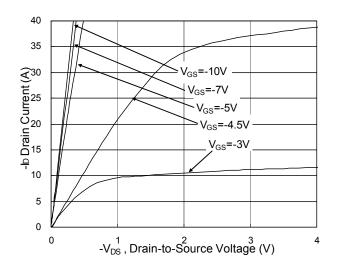
Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
I <sub>S</sub>	Continuous Source Current <sup>1,6</sup>	V <sub>G</sub> =V <sub>D</sub> =0V , Force Current			-4.0	Α
I <sub>SM</sub>	Pulsed Source Current <sup>2,6</sup>				-70	Α
$V_{SD}$	Diode Forward Voltage <sup>2</sup>	V <sub>GS</sub> =0V , I <sub>S</sub> =-1A , T <sub>J</sub> =25℃			-1.1	V
t <sub>rr</sub>	Reverse Recovery Time	-IF=-17.6A,dI/dt=100A/μs,T <sub>J</sub> =25℃		24		nS
Qrr	Reverse Recovery Charge			16		nC

#### Note:

- 1. The data tested by surface mounted on a 1 inch<sup>2</sup> FR-4 board with 2OZ copper, t<10sec.
- 2.The data tested by pulsed , pulse width  $\,\leq\,300\text{us}$  , duty cycle  $\,\leq\,2\%$
- 3.The EAS data shows Max. rating . The test condition is VDD=-25V,VGS=-10V,L=0.5mH,IAS=-38A
- 4.The power dissipation is limited by 150  $^{\circ}\mathrm{C}$  junction temperature
- 5.The Min. value is 100% EAS tested guarantee.
- 6. The data is theoretically the same as  $I_D$  and  $I_{DM}$ , in real applications, should be limited by total power dissipation.



## **Typical Characteristics**



**Fig.1 Typical Output Characteristics** 

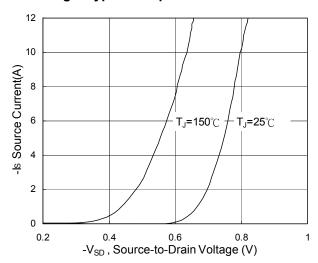


Fig.3 Forward Characteristics Of Reverse

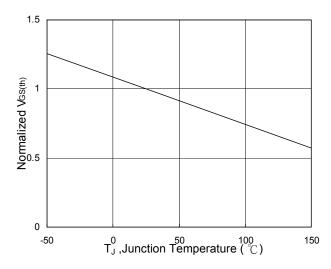


Fig.5 Normalized  $V_{GS(th)}$  vs.  $T_J$ 

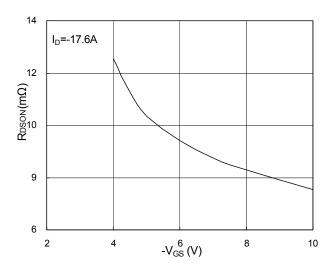


Fig.2 On-Resistance v.s Gate-Source

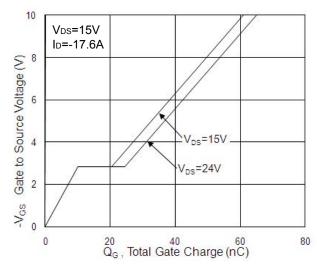


Fig.4 Gate-Charge Characteristics

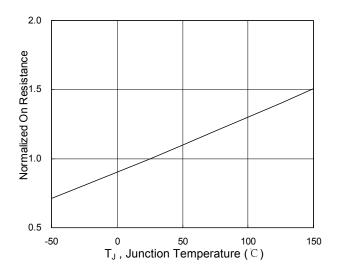
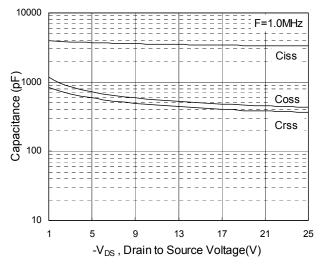


Fig.6 Normalized R<sub>DSON</sub> vs. T<sub>J</sub>





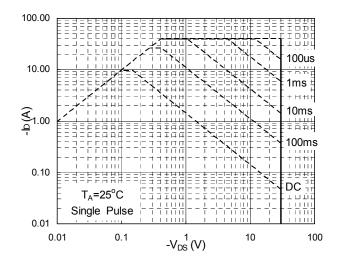


Fig.7 Capacitance

Fig.8 Safe Operating Area

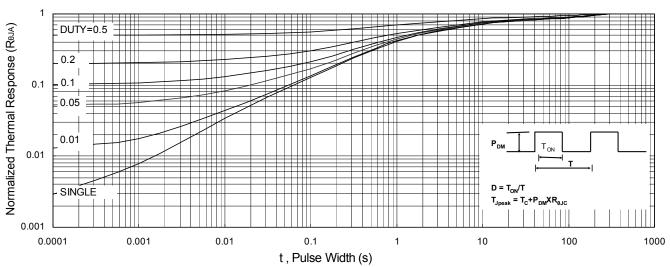


Fig.9 Normalized Maximum Transient Thermal Impedance

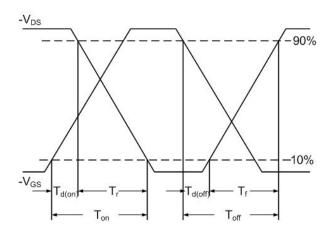


Fig.10 Switching Time Waveform

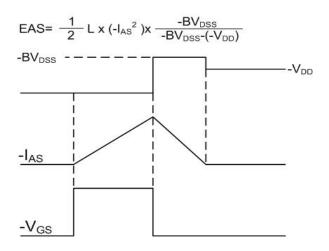


Fig.11 Unclamped Inductive Switching Waveform



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